

## SENSITIVE GATE TRIACS

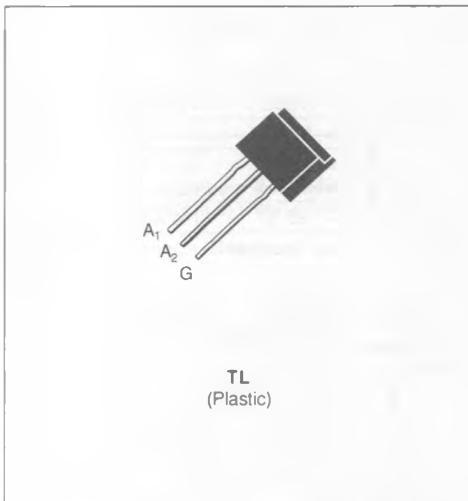
- GLASS PASSIVATED CHIP
- HIGH SURGE CURRENT

### DESCRIPTION

Low power triacs suited for 50 and 60 Hz up to 380 V<sub>RMS</sub>.

### APPLICATIONS

- CONTROL SPEED FOR LITTLE MOTORS ; ELECTRIC PUMP OR VENTILATOR, SEWING MACHINE
- RELAY, DETECTOR, ALARM SYSTEM
- ELECTRONIC STARTER FOR LAMP
- HIGH POWER TRIAC DRIVER



**TL**  
(Plastic)

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
I <sub>T(RMS)</sub>	RMS on-state Current (360° conduction angle)	T <sub>j</sub> = 40 °C	1	A
I <sub>T(RMS)</sub>	RMS on-state Current on Printed Circuit (360° conduction angle)	T <sub>a</sub> = 25 °C	0.77	A
I <sub>TSM</sub>	Non Repetitive Surge Peak on-state Current (T <sub>j</sub> initial = 25 °C - Half sine wave)	t = 8.3 ms	16	A
		t = 10 ms	15	
I <sup>2</sup> t	I <sup>2</sup> t Value for Fusing	t = 10 ms	1.125	A <sup>2</sup> s
dI/dt	Critical Rate of Rise of on-state Current (1)	Repetitive	10	A/μs
T <sub>stg</sub> T <sub>j</sub>	Storage and Operating Junction Temperature Range		- 40 to 150	°C
			- 40 to 110	°C

Symbol	Parameter	TLC111T	TLC221T	TLC331T	TLC381T	Unit
V <sub>DRM</sub>	Repetitive Peak off-state Voltage (2)	200	400	600	700	V

(1) I<sub>G</sub> = 50 mA dI/dt = 1 A/μs

(2) T<sub>j</sub> = 110 °C.

### THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
R <sub>th</sub> (j-a)	Junction to Ambient on Printed Circuit		75	°C/W
R <sub>th</sub> (j-l)	Junction-leads for 360° Conduction Angle (F = 50 Hz)		45	°C/W

**GATE CHARACTERISTICS** (maximum values)

$$P_{GM} = 2 \text{ W } (t_p = 10 \mu\text{s}) \quad I_{GM} = 1 \text{ A } (t_p = 10 \mu\text{s})$$

$$P_{G(AV)} = 0.1 \text{ W} \quad V_{GM} = 16 \text{ V } (t_p = 10 \mu\text{s})$$

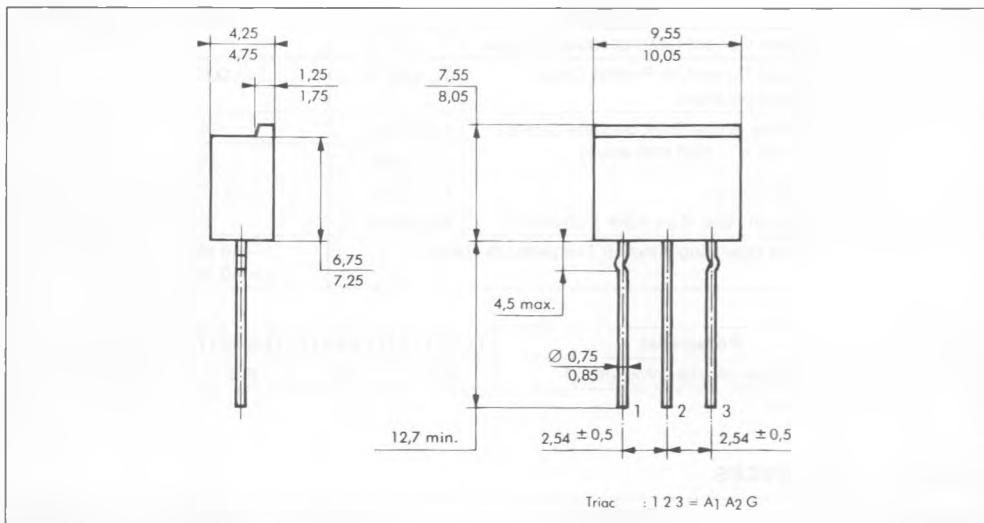
**ELECTRICAL CHARACTERISTICS**

Symbol	Test Conditions			Quadrants	Min.	Typ.	Max.	Unit
$I_{GT}$	$T_J = 25^\circ\text{C}$	$V_D = 12 \text{ V}$	$R_L = 33 \Omega$	I-II-III-IV			5	mA
	Pulse Duration > 20 $\mu\text{s}$							
$V_{GT}$	$T_J = 25^\circ\text{C}$	$V_D = 12 \text{ V}$	$R_L = 33 \Omega$	I-II-III-IV			1.5	V
	Pulse Duration > 20 $\mu\text{s}$							
$V_{GD}$	$T_J = 110^\circ\text{C}$	$V_D = V_{DRM}$	$R_L = 3.3 \text{ k}\Omega$	I-II-III-IV	0.2			V
$I_H^*$	$T_J = 25^\circ\text{C}$	$I_T = 100 \text{ mA}$	Gate Open				15	mA
$I_L$	$T_J = 25^\circ\text{C}$	$V_D = 12 \text{ V}$	$I_G = 10 \text{ mA}$	I-II-III-IV			15	mA
	Pulse Duration > 20 $\mu\text{s}$							
$V_{TM}^*$	$T_J = 25^\circ\text{C}$	$I_{TM} = 1.4 \text{ A}$	$t_p = 10 \text{ ms}$				1.8	V
$I_{DRM}^*$	$V_{DRM}$ Specified		$T_J = 25^\circ\text{C}$				0.01	mA
			$T_J = 110^\circ\text{C}$				0.75	
$dv/dt^*$	$T_J = 110^\circ\text{C}$	Gate Open				10		V/ $\mu\text{s}$
	Linear Slope up to $V_D = 67\% V_{DRM}$							
$(dv/dt)_c^*$	$T_J = 40^\circ\text{C}$	$V_D = V_{DRM}$	$I_T = 1.4 \text{ A}$			1		V/ $\mu\text{s}$
	$(di/dt)_c = 0.4 \text{ A/ms}$							
$t_{gt}$	$T_J = 25^\circ\text{C}$	$V_D = V_{DRM}$	$I_T = 1.4 \text{ A}$	I-II-III-IV		3		$\mu\text{s}$
	$I_G = 100 \text{ mA}$	$di_G/dt = 1 \text{ A}/\mu\text{s}$						

\* For either polarity of electrode A<sub>2</sub> voltage with reference to electrode A<sub>1</sub>.

**PACKAGE MECHANICAL DATA**

TL Plastic



Cooling method : by convection (method A)

Marking : type number

Weight : 0.8 g

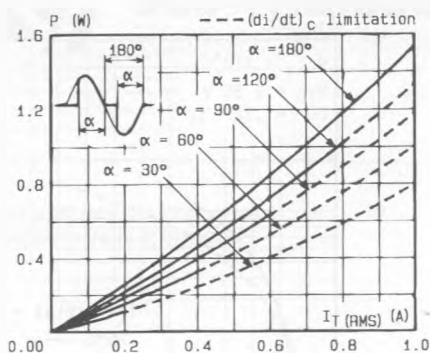


Fig.1 - Maximum mean power dissipation versus RMS on-state current ( $F = 60$  Hz).

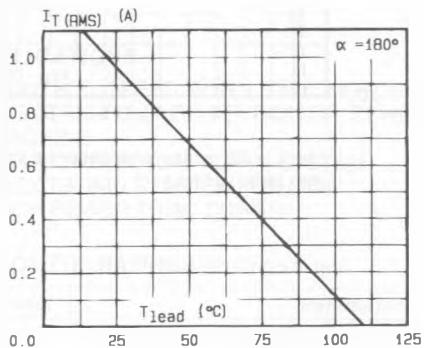


Fig.3 - RMS on-state current versus lead temperature.

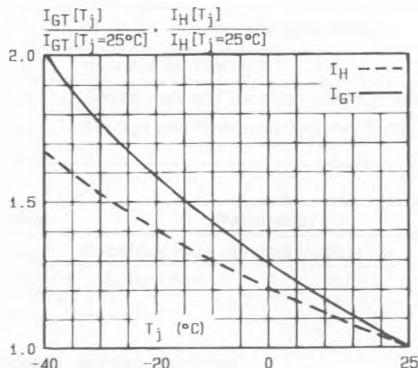


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

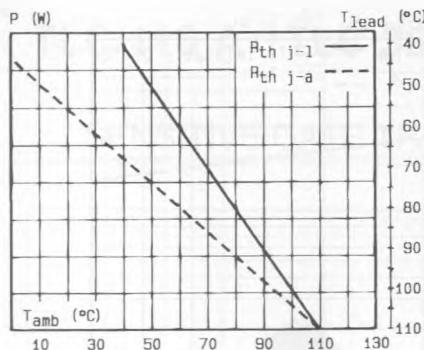


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{lead}$ ). resistances heatsink + contact.

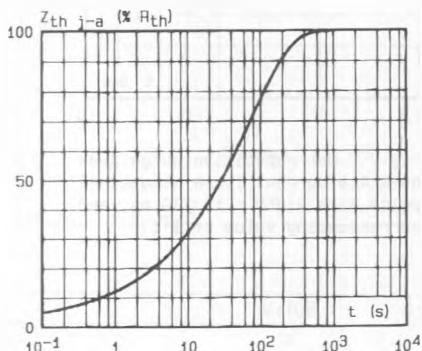


Fig.4 - Thermal transient impedance junction to ambient versus pulse duration.

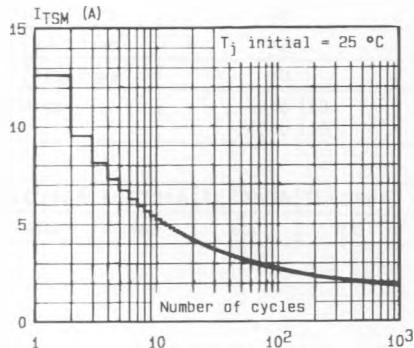


Fig.6 - Non repetitive surge peak on state current versus number of cycles.

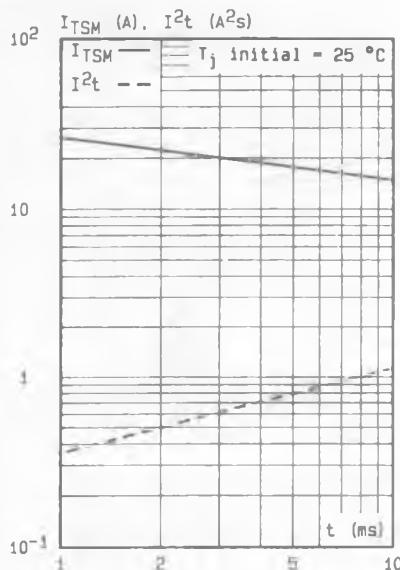


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

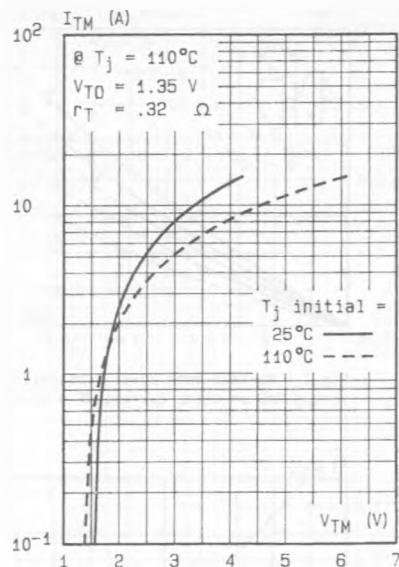


Fig.8 - On-state characteristics (maximum values).